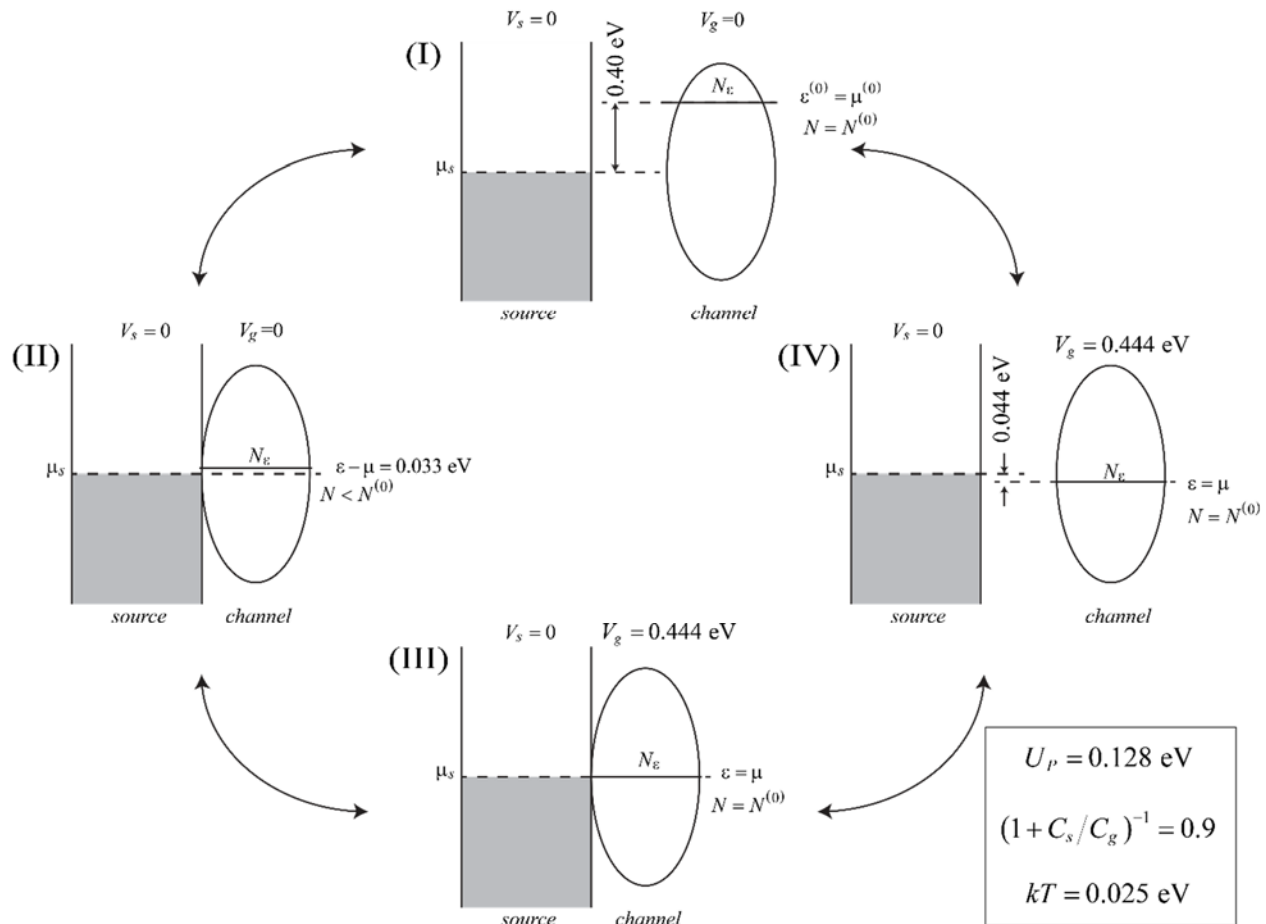


Nanocapacitor**Cyclic process**

Consider the charging and neutralizing of a nanocapacitor shown in the energy diagram below.



In the neutral, isolated channel, we will call the energy level $\epsilon^{(0)}$ and the chemical potential $\mu^{(0)}$. The energy level in the channel has a degeneracy of N_ϵ . In its neutral state, the level contains $N^{(0)}$ electrons.

Explanation

Let's take the channel potential to be

$$U = U_p \cdot \Delta N - U_L$$

When the channel is in contact with the source, the potential terms are

$$U_p \cdot \Delta N = -\frac{qQ}{C_s + C_g} = -\frac{q^2}{C_s + C_g} \cdot (N - N^{(0)}) \quad \text{and} \quad U_L = \frac{qV_g}{1 + C_s/C_g}$$

When the channel is isolated from the source, the potential terms are

$$U_p \cdot \Delta N = -\frac{qQ}{C_g} = -\frac{q^2}{C_g} \cdot (N - N^{(0)}) \quad \text{and} \quad U_L = qV_g$$

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It is given in this example that $\varepsilon^{(0)} = \mu^{(0)}$, so $N^{(0)} = (0.5)N_\varepsilon$.

(I) No contact, no bias, neutral

Starting in isolation with $V_g = 0$ and $Q = 0$. Then

$$\varepsilon = \varepsilon^{(0)}, \mu = \mu^{(0)} \text{ and } N = N^{(0)}.$$

So $U_p \cdot \Delta N = 0$ and $U_L = 0$, giving $U = 0$.

(II) Contact, no bias

Contact between the source and channel gives $\mu = \mu_s$. In general, we still have $\varepsilon \neq \varepsilon^{(0)}$ and $N \neq N^{(0)}$.

Their exact values require a self-consistent solution. Now $U_p \cdot \Delta N \neq 0$, but $U_L = 0$, so $U = U_p \cdot \Delta N$

(III) Contact, bias, neutral

Now let's find the exact bias that gives $N = N^{(0)}$ ($Q = 0$). We still have $\mu = \mu_s$. For neutrality, we must have $\varepsilon - \mu = \varepsilon^{(0)} - \mu^{(0)} = (\varepsilon^{(0)} + U) - \mu$. This indicates that $\mu - \mu^{(0)} = U$. Since $U_p \cdot \Delta N = 0$, we have

$$U = -U_L = -\frac{qV_g}{1 + C_s/C_g}$$

So the needed gate bias is

$$V_g = (1 + C_s/C_g) \cdot (\mu - \mu^{(0)})/q$$

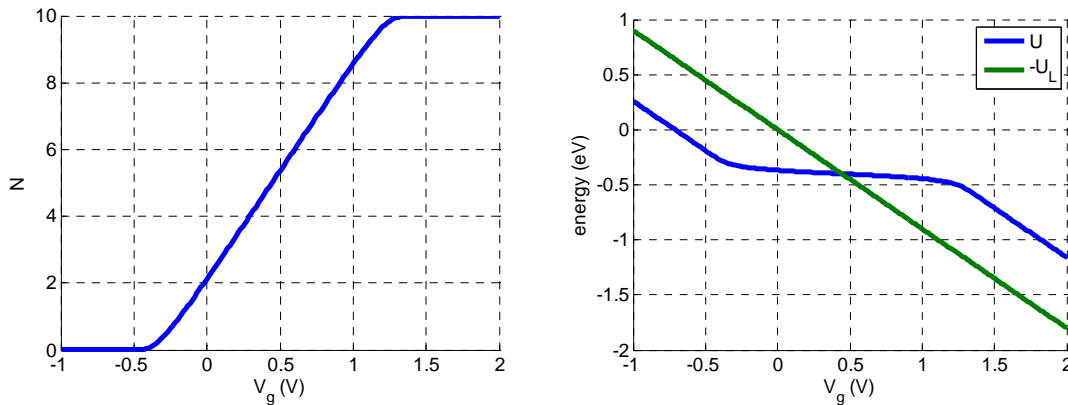
(IV) No contact, bias, neutral

Now let's keep the same gate voltage and break contact with the source. We will have $Q = 0$ and $N = N^{(0)}$. So $U_p \cdot \Delta N = 0$, but without the source-channel capacitance, we have $U_L = qV_g$. Then

$U = -U_L = -qV_g$. We have $\varepsilon - \mu = \varepsilon^{(0)} - \mu^{(0)}$, so $\varepsilon - \varepsilon^{(0)} = \mu - \mu^{(0)} = -qV_g$. Also $\mu - \mu_s = \mu^{(0)} - \mu_s - qV_g$.

Self-consistent solutions

Let's evaluate the channel charge and energy level as functions of gate voltage when in contact with the source using the numbers in the figure: $U_p = 0.128$ eV, $1/(1 + C_s/C_g) = 0.9$, $kT = 0.025$ eV.



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In case (I), we have $\mu^{(0)} - \mu_s = 0.40 \text{ eV}$. In case (II), the self-consistent solution tells us that, with $V_g = 0$, we have $N = (0.213) \cdot N_e$ and $\varepsilon - \mu_s = 0.033 \text{ eV}$. In case (III), we find the exact gate voltage to neutralize the channel is $V_g = (0.40 \text{ eV})/0.9 = 0.444 \text{ eV}$. In case (IV), $\varepsilon = \varepsilon^{(0)} - 0.444 \text{ eV}$, which is 0.044 eV below μ_s .